

Josephson effect in ballistic graphene

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We solve the Dirac–Bogoliubov–de Gennes equation in an impurity-free superconductor–normal-metal–superconductor junction, to determine the maximal supercurrent I_c that can flow through an undoped strip of graphene with heavily doped superconducting electrodes. The result $I_c \approx (W/L)e\Delta_0/\hbar$ is determined by the superconducting gap Δ_0 and by the aspect ratio of the junction (length L small relative to the width W and to the superconducting coherence length). Moving away from the Dirac point of zero doping, we recover the usual ballistic result $I_c \approx (W/\lambda_F)e\Delta_0/\hbar$, in which the Fermi wavelength λ_F takes over from L . The product $I_c R_N \approx \Delta_0/e$ of the critical current and normal-state resistance retains its universal value (up to a numerical prefactor) on approaching the Dirac point.

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While the Josephson effect was originally discovered in a tunnel junction,¹ any weak link between two superconductors can support a dissipationless current in equilibrium.² The current $I(\phi)$ varies periodically with the phase difference ϕ of the pair potential in the two superconductors, reaching a maximum I_c (the critical current) which is characteristic of the strength of the link. A measure of the coupling strength is the resistance R_N of the junction when the superconductors are in the normal state. The product $I_c R_N$ increases as the separation L of the two superconductors becomes smaller and smaller, until it saturates at a value of order Δ_0/e , determined only by the excitation gap Δ_0 in the superconductors—but independent of the coupling strength. This phenomenology has been well established in a variety of superconductor–normal-metal–superconductor (SNS) junctions³ and forms the basis of operation of the Josephson field-effect transistor.^{4,5}

A new class of weak links has now become available for research,⁶ in which the superconductors are coupled by a monatomic layer of carbon (graphene). The low-lying excitations in this material are described by a relativistic wave equation, the Dirac equation. They are massless, having a velocity v that is independent of energy, and gapless, occupying conduction and valence bands that touch at discrete points (Dirac points) in reciprocal space.⁷ Graphene thus provides a unique opportunity to explore the physics of the “relativistic Josephson effect” (which had remained unexplored in earlier work⁸ on relativistic effects in high-temperature and heavy-fermion superconductors). We address this problem here in the framework of the Dirac–Bogoliubov–de Gennes (DBdG) equation of Ref. 9.

The basic question that we seek to answer is what happens to the critical current as we approach the Dirac point of zero carrier concentration. Earlier theories^{11–13} have found that undoped graphene has a quantum-limited conductivity of order e^2/h , in the absence of any impurities or lattice defects. We find that the critical current is given, up to numerical coefficients of order unity, by

$$I_c \approx \frac{e\Delta_0}{\hbar} \max(W/L, 2\pi W/\lambda_F), \quad (1)$$

in the short-junction regime $L \ll W, \xi$ (with $\xi = \hbar v/\Delta_0$ the superconducting coherence length, W the width of the junction, and λ_F the Fermi wavelength in the normal region). At the Dirac point $\lambda_F \rightarrow \infty$, so the critical current reaches its minimal value of $(e\Delta_0/\hbar)W/L$. Since the normal-state resistance has its maximal value $R_N \approx (h/e^2)L/W$ at the Dirac point, the $I_c R_N$ product remains of order Δ_0/e as the carrier concentration is reduced to zero.

The system considered is shown schematically in Fig. 1. A layer of graphene in the x - y plane is covered by superconducting electrodes in the regions $x < -L/2$ and $x > L/2$. The normal region $|x| < L/2$ has electron and hole excitations described by the DBdG equation,^{9,10}

$$\begin{pmatrix} H_0 - \mu & 0 \\ 0 & \mu - H_0 \end{pmatrix} \begin{pmatrix} \Psi_e \\ \Psi_h \end{pmatrix} = \varepsilon \begin{pmatrix} \Psi_e \\ \Psi_h \end{pmatrix}. \quad (2)$$

Here $H_0 = -i\hbar v(\sigma_x \partial_x + \sigma_y \partial_y)$ is the Dirac Hamiltonian, $\varepsilon > 0$ is the excitation energy, and μ is the chemical potential or Fermi energy in the normal region (measured with respect to the Dirac point, so that $\mu = 0$ corresponds to undoped graphene). The electron wave functions Ψ_e and the hole wave functions Ψ_h have opposite spin and valley indices, which are not written explicitly. (A fourfold degeneracy factor will be added in the final results.) The Pauli matrices σ_i in H_0 operate on the isospin index, which labels the two sub-

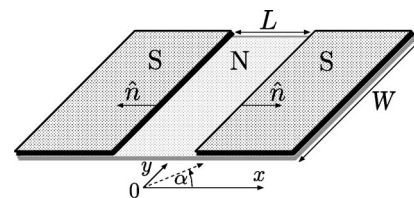


FIG. 1. Schematic of a graphene layer, partially covered by two superconducting electrodes (S). A dissipationless supercurrent flows in equilibrium through the normal region (N), depending on the phase difference between the two superconductors. Separate gate electrodes (not shown) make it possible to vary independently the carrier concentration in the normal and superconducting regions of the graphene layer.

lattices of the honeycomb lattice of carbon atoms.

Andreev reflection at a normal-metal–superconductor (NS) interface couples Ψ_e and Ψ_h . This coupling may be described *globally* by a scattering matrix, as was done in Ref. 9 to determine the conductance of a NS junction. Here we follow a different approach, more suited to determine the energy spectrum (and therefrom the Josephson current). In this approach electrons and holes are coupled *locally* by means of a boundary condition on the wave function in the normal region.

We consider the energy range $\varepsilon < \Delta_0$ below the excitation gap Δ_0 in the superconductor, where the spectrum is discrete. At a point \mathbf{r} on the NS interface (with unit vector $\hat{\mathbf{n}}$ pointing from N to S, perpendicular to the interface), the boundary condition takes the form

$$\Psi_h(\mathbf{r}) = U\Psi_e(\mathbf{r}), \quad (3)$$

$$U = \frac{1}{\Delta}(\varepsilon - i\sqrt{|\Delta|^2 - \varepsilon^2}\hat{\mathbf{n}} \cdot \boldsymbol{\sigma}) = e^{-i\Phi - i\beta\hat{\mathbf{n}} \cdot \boldsymbol{\sigma}}. \quad (4)$$

Here $\Delta = \Delta_0 e^{i\Phi}$ is the complex pair potential in S, $\boldsymbol{\sigma} = (\sigma_x, \sigma_y)$ is the vector of Pauli matrices, and $\beta = \arccos(\varepsilon/\Delta_0) \in (0, \pi/2)$.

The relation (3) follows from the DBdG equation,^{9,14} under three assumptions characterizing an “ideal” NS interface: (I) The Fermi wavelength λ_F' in S is sufficiently small that $\lambda_F' \ll \xi, \lambda_F$, where $\lambda_F = \hbar v / \mu$ is the Fermi wavelength in N and $\xi = \hbar v / \Delta_0$ is the superconducting coherence length; (II) the interface is smooth and impurity-free on the scale of ξ ; (III) there is no lattice mismatch at the NS interface, so the honeycomb lattice of graphene is unperturbed at the boundary. The absence of lattice mismatch might be satisfied by depositing the superconductor on top of a heavily doped region of graphene. As in the case of a semiconductor two-dimensional electron gas,^{15,16} we expect that such an extended superconducting contact can be effectively described by a pair potential Δ in the x - y plane (even though graphene by itself is not superconducting).

The particle current density out of the normal region, given by

$$j_{\text{particle}} = v\Psi_e^* \hat{\mathbf{n}} \cdot \boldsymbol{\sigma} \Psi_e - v\Psi_h^* \hat{\mathbf{n}} \cdot \boldsymbol{\sigma} \Psi_h, \quad (5)$$

should vanish for $\varepsilon < \Delta_0$, because subgap excitations decay over a length ξ in S. (The possibility of a subgap excitation entering the superconductor at one point along the boundary and exiting at another point within a distance ξ is excluded by assumption II.) By substituting the boundary condition (3) one indeed finds that $j_{\text{particle}} = 0$, since U is a unitary matrix which commutes with $\hat{\mathbf{n}} \cdot \boldsymbol{\sigma}$.

In the SNS junction the normal region has two interfaces with the superconductor, one at $x = -L/2$ (with superconducting phase $\Phi = \phi/2$ and outward normal $\hat{\mathbf{n}} = -\hat{\mathbf{x}}$) and another at $x = L/2$ (with $\Phi = -\phi/2$ and $\hat{\mathbf{n}} = \hat{\mathbf{x}}$). The boundary condition (3) at the points $\mathbf{r}_{\pm} = (\pm L/2, y)$ thus takes the form

$$\Psi_h(\mathbf{r}_-) = U(\varepsilon)\Psi_e(\mathbf{r}_-), \quad \Psi_h(\mathbf{r}_+) = U^{-1}(\varepsilon)\Psi_e(\mathbf{r}_+), \quad (6)$$

$$U(\varepsilon) = e^{-i\phi/2 + i\beta\sigma_x}, \quad \beta = \arccos(\varepsilon/\Delta_0). \quad (7)$$

Since the wave vector k_y parallel to the NS interface is conserved upon Andreev reflection, we may solve the problem for a given $k_y \equiv q$. The transfer matrix $\mathcal{M}(\varepsilon, q)$ relates the states at the two ends of the normal region:

$$\Psi_e(\mathbf{r}_+) = \mathcal{M}(\varepsilon, \mathbf{q})\Psi_e(\mathbf{r}_-), \quad \Psi_h(\mathbf{r}_+) = \mathcal{M}(-\varepsilon, \mathbf{q})\Psi_h(\mathbf{r}_-). \quad (8)$$

(For ease of notation, the q dependence will not be written explicitly in what follows.) The condition for a bound state (the Andreev level) in the SNS junction is that the transfer matrix for the round trip from \mathbf{r}_- to \mathbf{r}_+ and back to \mathbf{r}_- has an eigenvalue equal to unity. This condition can be written in the form of a determinant,

$$\text{Det}[1 - \mathcal{M}^{-1}(\varepsilon)U(\varepsilon)\mathcal{M}(-\varepsilon)U(\varepsilon)] = 0, \quad (9)$$

which we have to solve for ε as a function of q and ϕ .

The electron transfer matrix $\mathcal{M}(\varepsilon)$ is readily obtained from the Dirac equation,

$$\mathcal{M} = \Lambda e^{ikL\sigma_z} \Lambda, \quad (10)$$

$$\Lambda = \Lambda^{-1} = (2 \cos \alpha)^{-1/2} \begin{pmatrix} e^{-i\alpha/2} & e^{i\alpha/2} \\ e^{i\alpha/2} & -e^{-i\alpha/2} \end{pmatrix}, \quad (11)$$

$$\alpha(\varepsilon) = \arcsin\left(\frac{\hbar v q}{\varepsilon + \mu}\right), \quad (12)$$

$$k(\varepsilon) = (\hbar v)^{-1}(\varepsilon + \mu) \cos \alpha(\varepsilon). \quad (13)$$

The angle α is the angle of incidence of the electron, and k is its longitudinal wave vector.

Evaluation of the determinant (9) leads after some algebra to the quantization condition

$$\begin{aligned} \cos \phi = & \left(\cos \theta_+ \cos \theta_- + \frac{\sin \theta_+ \sin \theta_-}{\cos \alpha_+ \cos \alpha_-} \right) \cos 2\beta \\ & + \left(\frac{\sin \theta_+ \cos \theta_-}{\cos \alpha_+} - \frac{\cos \theta_+ \sin \theta_-}{\cos \alpha_-} \right) \sin 2\beta \\ & - \sin \theta_+ \sin \theta_- \tan \alpha_+ \tan \alpha_-, \end{aligned} \quad (14)$$

where we abbreviated $\alpha_{\pm} = \alpha(\pm\varepsilon)$, $\theta_{\pm} = k(\pm\varepsilon)L$.

We introduce a finite width W to quantize the transverse wave vectors, $q \rightarrow q_n$, $n=0, 1, 2, \dots$, and denote by $\rho_n(\varepsilon, \phi)$ the density of states in mode n . The Josephson current at zero temperature is then given by

$$I(\phi) = -\frac{4e}{\hbar} \frac{d}{d\phi} \int_0^{\infty} d\varepsilon \sum_{n=0}^{\infty} \rho_n(\varepsilon, \phi) \varepsilon, \quad (15)$$

where the factor of 4 accounts for the twofold spin and valley degeneracies. To be definite we take “infinite mass” boundary conditions at $y=0, W$, for which¹² $q_n = (n + 1/2)\pi/W$. (For $W \gg L$ the choice of boundary conditions becomes irrelevant.) At the Fermi level, the lowest $N(\mu) = \mu W / \pi \hbar v$ modes are propagating (real k), while the higher modes are evanescent (imaginary k).

We analyze the Josephson effect in the experimentally

most relevant *short-junction* regime that the length L of the normal region is small relative to the superconducting coherence length ξ . In terms of energy scales, this condition requires $\Delta_0 \ll \hbar v/L$. To leading order in the small parameter $\Delta_0 L/\hbar v$ we may substitute $\alpha_{\pm} \rightarrow \alpha(0)$, $\theta_{\pm} \rightarrow k(0)L$ in the quantization condition (14). The solution is a single bound state per mode,

$$\varepsilon_n(\phi) = \Delta_0 \sqrt{1 - \tau_n \sin^2(\phi/2)}, \quad (16)$$

$$\tau_n = \frac{k_n^2}{k_n^2 \cos^2(k_n L) + (\mu/\hbar v)^2 \sin^2(k_n L)}, \quad (17)$$

with $k_n = [(\mu/\hbar v)^2 - q_n^2]^{1/2}$. This expression for the Andreev levels in terms of a normal-state transmission probability τ_n has the usual form for a short SNS junction.¹⁷ Comparison with Ref. 12 shows that τ_n is indeed the transmission probability for a ballistic strip of graphene between two heavily doped electrodes in the normal state ($\Delta_0 = 0$, $\lambda'_F \ll \lambda_F$). The normal-state resistance R_N is thus given by

$$R_N^{-1} = \frac{4e^2}{h} \sum_{n=0}^{\infty} \tau_n. \quad (18)$$

Substitution of $\rho_n(\varepsilon, \phi) = \delta[\varepsilon - \varepsilon_n(\phi)]$ into Eq. (15) gives the supercurrent due to the discrete spectrum,

$$I(\phi) = \frac{e\Delta_0}{\hbar} \sum_{n=0}^{\infty} \frac{\tau_n \sin \phi}{[1 - \tau_n \sin^2(\phi/2)]^{1/2}}. \quad (19)$$

Contributions to the supercurrent from the continuous spectrum are smaller by a factor L/ξ and may be neglected in the short-junction regime.¹⁸ For $L \ll W$ the summation over n may be replaced by an integration. The resulting critical current I_c and the $I_c R_N$ product are plotted as a function of μ in Fig. 2.

The limiting behavior at the Dirac point ($\mu \ll \hbar v/L$) for a short and wide normal region ($L \ll W, \xi$) is

$$I(\phi) = \frac{e\Delta_0}{\hbar} \frac{2W}{\pi L} \cos(\phi/2) \operatorname{arctanh}[\sin(\phi/2)], \quad (20)$$

$$I_c = 1.33 \frac{e\Delta_0}{\hbar} \frac{W}{\pi L}, \quad I_c R_N = 2.08 \Delta_0/e. \quad (21)$$

These results for *ballistic* graphene at the Dirac point are formally identical to those of a *disordered* normal metal (Fermi wave vector k_F , mean free path l),^{17,19} upon substitution $k_F l \rightarrow 1$. This correspondence is consistent with the finding of Ref. 12 that ballistic Dirac fermions have the same shot noise as diffusive nonrelativistic electrons.

In the opposite regime $\mu \gg \hbar v/L$ we have instead (still for $L \ll W, \xi$) the result

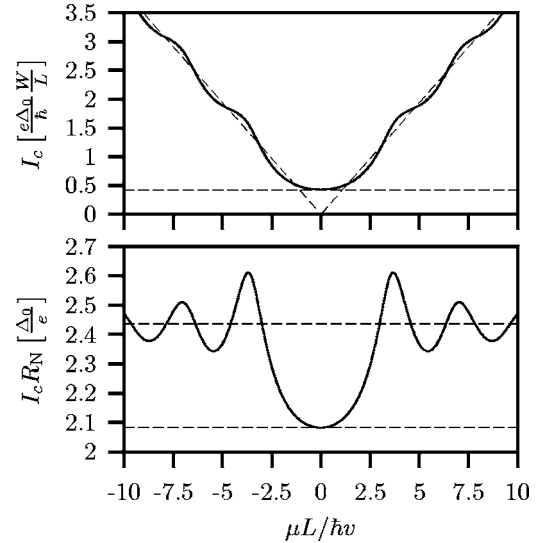


FIG. 2. Critical current I_c and $I_c R_N$ product of a ballistic Josephson junction (length L short compared to the width W and superconducting coherence length ξ), as a function of the Fermi energy μ in the normal region. The asymptotes (21) and (22) are indicated by dashed lines.

$$I_c = 1.22 \frac{e\Delta_0}{\hbar} \frac{\mu W}{\pi \hbar v}, \quad I_c R_N = 2.44 \Delta_0/e. \quad (22)$$

(We do not have a simple analytic expression for the ϕ dependence in this regime.) The critical current (22) is about half the ideal ballistic value^{17,20} $I_c = 2Ne\Delta_0/\hbar$, with $N = \mu W/\pi \hbar v$ the number of propagating modes (per spin and valley). This reduction is due to the mismatch in Fermi wavelength at the NS interfaces. Equations (21) and (22) together contain the scaling behavior (1) with $\lambda_F = \hbar v/\mu$ announced in the introduction.

In conclusion, we have shown that a Josephson junction in graphene can carry a nonzero supercurrent even if the Fermi level is tuned to the point of zero carrier concentration. At this Dirac point, the current-phase relationship has the same form as in a disordered normal metal—but without any impurity scattering. Instead of being independent of the length L of the junction, as expected for a short ballistic Josephson junction, the critical current I_c at the Dirac point has diffusionlike scaling proportional $1/L$. Since the normal-state resistance $R_N \propto L$, the $I_c R_N$ product remains fixed at the superconducting gap (up to a numerical prefactor) as the Fermi level passes through the Dirac point. This unusual “quasidiffusive” scaling of the Josephson effect in undoped graphene should be observable in submicrometer scale junctions.

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